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FDP8447L

N-Channel PowerTrench® MOSFET

40V, 50A, 8.7mΩ

Features

- Max $r_{DS(on)}$ = 8.7mΩ at $V_{GS} = 10V$, $I_D = 14A$
- Max $r_{DS(on)}$ = 11.2mΩ at $V_{GS} = 4.5V$, $I_D = 11A$
- Fast Switching
- RoHS Compliant

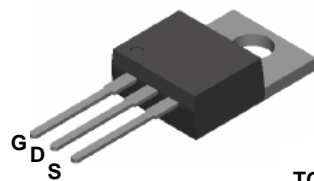


General Description

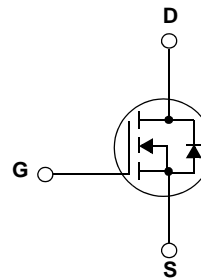
This N-Channel MOSFET has been produced using Fairchild Semiconductor's proprietary PowerTrench technology to deliver low $r_{DS(on)}$ and optimized BV_{DSS} capability to offer superior performance benefit in the application.

Applications

- Inverter
- Power Supplies



TO-220
FDP Series



MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DS}	Drain to Source Voltage	40	V
V_{GS}	Gate to Source Voltage	±20	V
I_D	Drain Current -Continuous (Package limited) $T_C = 25^\circ\text{C}$	50	A
	-Continuous (Silicon limited) $T_C = 25^\circ\text{C}$	65	
	-Continuous $T_A = 25^\circ\text{C}$ (Note 1)	12	
	-Pulsed	100	
E_{AS}	Drain-Source Avalanche Energy (Note 3)	153	mJ
P_D	Power Dissipation $T_C = 25^\circ\text{C}$	60	W
	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1)	2	
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	2.1	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1)	62.5	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP8447L	FDP8447L	TO-220AB	Tube	N/A	50units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$, $V_{GS} = 0\text{V}$	40			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$, referenced to 25°C		34		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 32\text{V}$,			1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$, $V_{DS} = 0\text{V}$			± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250\mu\text{A}$	1	1.7	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$, referenced to 25°C		-6		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10\text{V}$, $I_D = 14\text{A}$		7.7	8.7	m Ω
		$V_{GS} = 4.5\text{V}$, $I_D = 11\text{A}$		8.9	11.2	
		$V_{GS} = 10\text{V}$, $I_D = 14\text{A}$, $T_J = 125^\circ\text{C}$		12.1	13.7	
g_{FS}	Forward Transconductance	$V_{DD} = 5\text{V}$, $I_D = 14\text{A}$		74		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 20\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$		1880	2500	pF
C_{oss}	Output Capacitance			245	325	pF
C_{riss}	Reverse Transfer Capacitance			150	225	pF
R_g	Gate Resistance	$f = 1\text{MHz}$		1.4		Ω

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 20\text{V}$, $I_D = 14\text{A}$, $V_{GS} = 10\text{V}$, $R_{GEN} = 6\Omega$		9	18	ns
t_r	Rise Time			7	14	ns
$t_{d(off)}$	Turn-Off Delay Time			28	45	ns
t_f	Fall Time			4	10	ns
Q_g	Total Gate Charge		$V_{GS} = 0\text{V}$ to 10V	$V_{DD} = 20\text{V}$, $I_D = 14\text{A}$	35	49
Q_g	Total Gate Charge	$V_{GS} = 0\text{V}$ to 5V	19		27	nC
Q_{gs}	Gate to Source Charge		4.7			nC
Q_{gd}	Gate to Drain "Miller" Charge		6.2			nC

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{V}$, $I_S = 14\text{A}$ (Note 2)		0.8	1.2	V
t_{rr}	Reverse Recovery Time	$I_F = 14\text{A}$, $di/dt = 100\text{A}/\mu\text{s}$		28	42	ns
Q_{rr}	Reverse Recovery Charge			22	33	nC

NOTES:

- $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.
- Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%.
- Starting $T_J = 25^\circ\text{C}$, $L = 1\text{mH}$, $I_{AS} = 17.5\text{A}$, $V_{DD} = 40\text{V}$, $V_{GS} = 10\text{V}$.

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

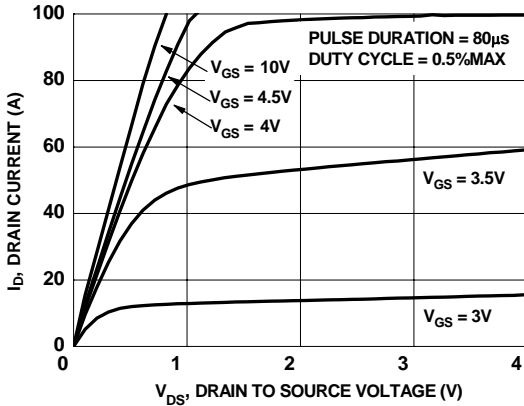


Figure 1. On-Region Characteristics

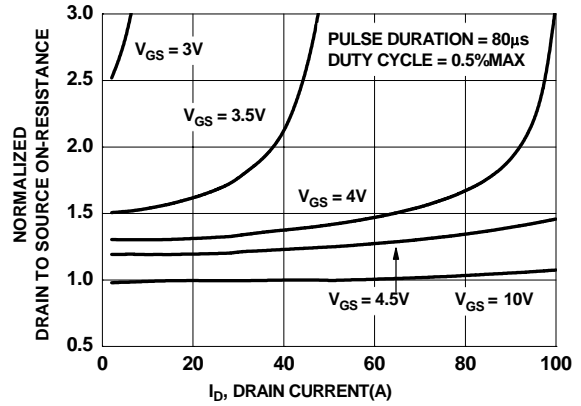


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

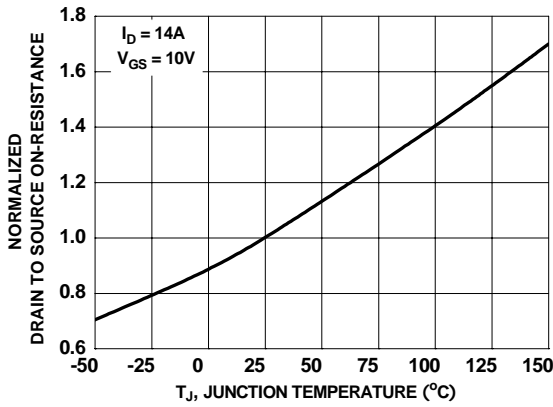


Figure 3. Normalized On-Resistance vs Junction Temperature

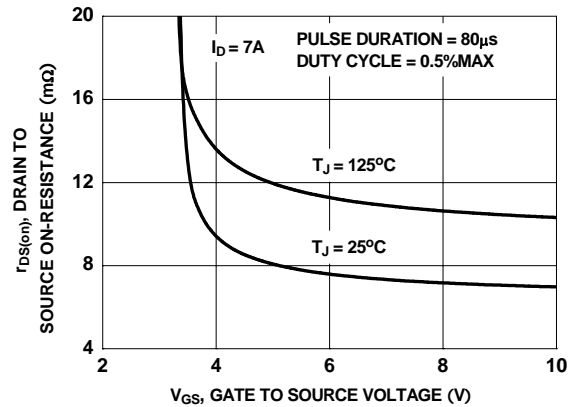


Figure 4. On-Resistance vs Gate to Source Voltage

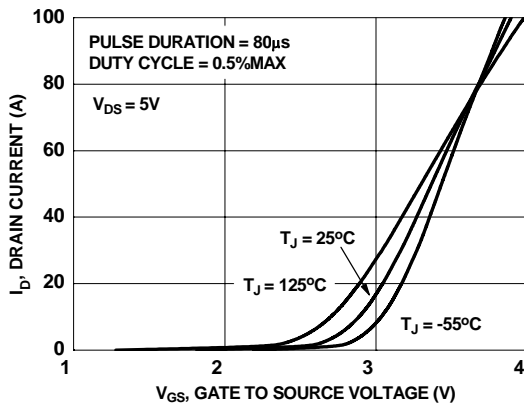


Figure 5. Transfer Characteristics

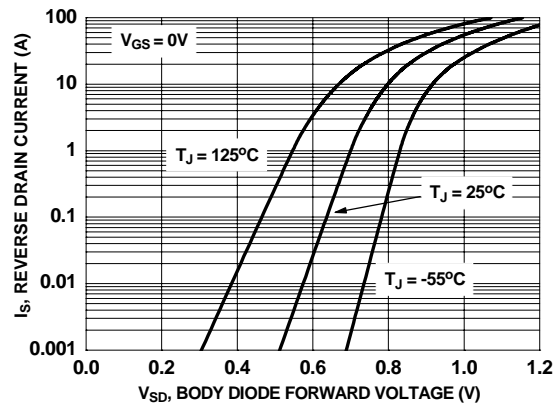


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

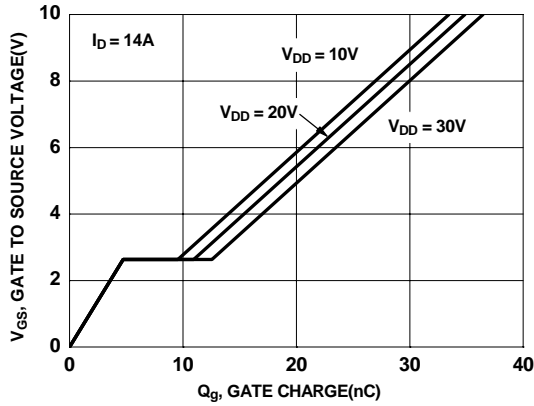


Figure 7. Gate Charge Characteristics

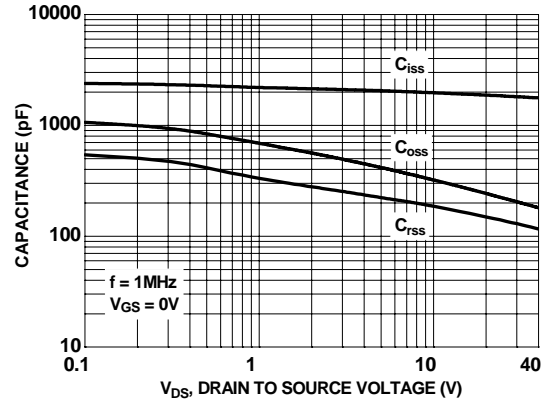


Figure 8. Capacitance vs Drain to Source Voltage

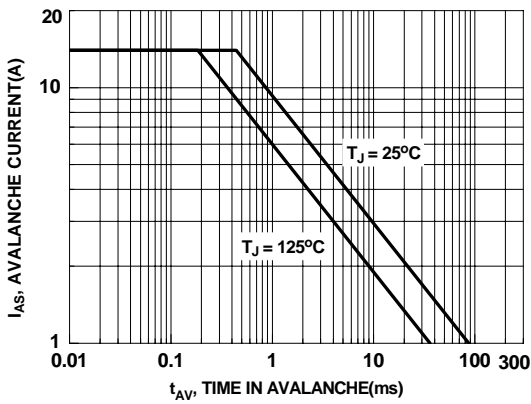


Figure 9. Unclamped Inductive Switching Capability

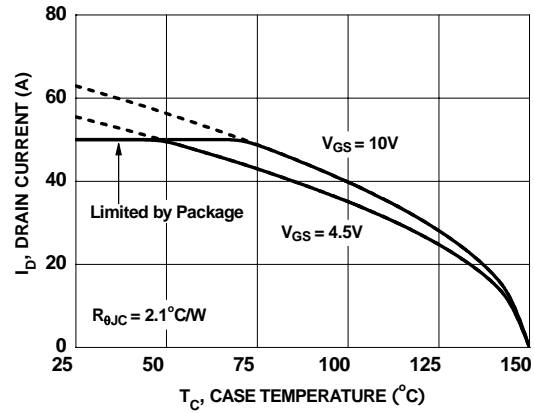


Figure 10. Maximum Continuous Drain Current vs Case Temperature

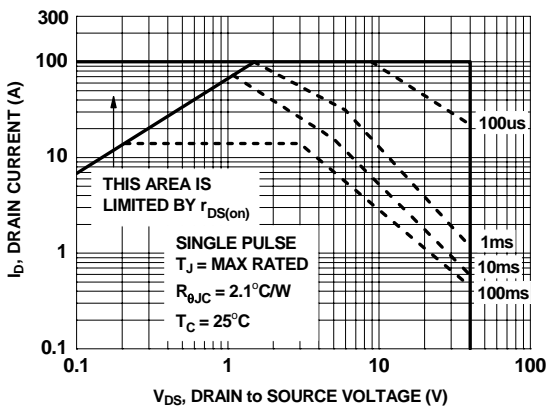


Figure 11. Forward Bias Safe Operating Area

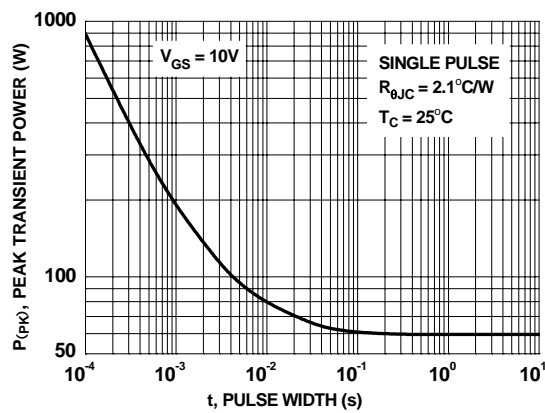


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

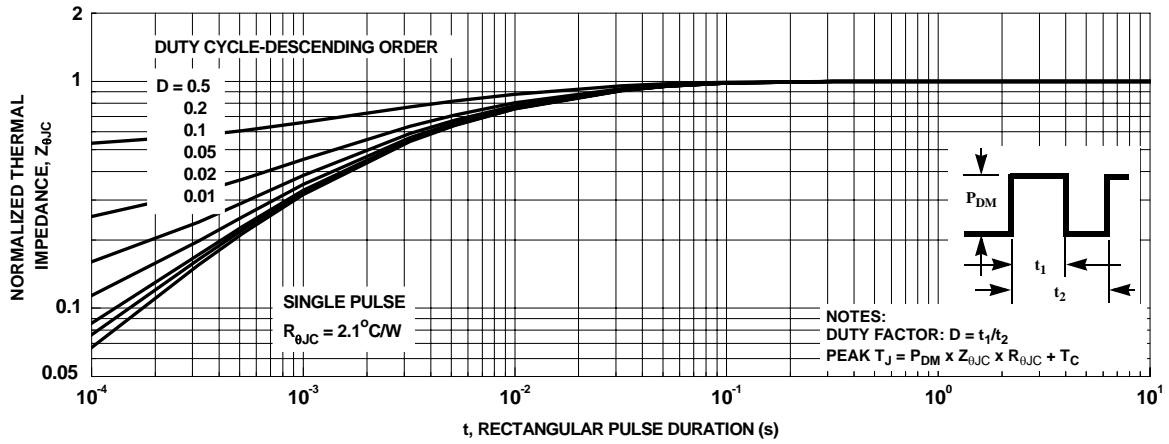


Figure 13. Transient Thermal Response Curve



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